



#### 200 MHz Variable Gain Photoreceiver



The image shows model OE-300-SI-10-FST with 1.035"-40 threaded flange and coupler ring.

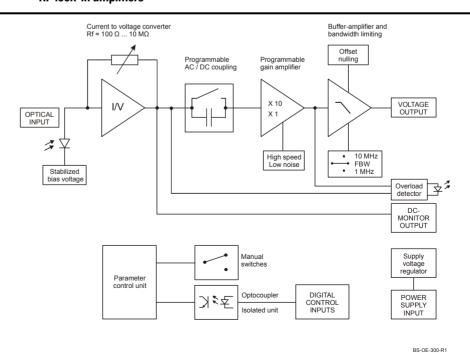
Features

- Adjustable transimpedance gain from 10<sup>2</sup> to 10<sup>8</sup> V/A
- Wide bandwidth up to 200 MHz
- Si-PIN photodiode covering the 400 to 1000 nm wavelength range
- Large optical detector size 1 x 1 mm
- . High dynamic input range up to 10 mW optical power
- Very low noise, NEP down to 76 fW/√Hz
- Switchable low pass filters for minimizing wideband noise
- Threaded 1.035"-40 and unthreaded 25 mm dia. free space input available, compatible with many optical standard accessories
- 1.035"-40 input easily convertible to fiber optic input with optional adapter
- Full manual and remote control capability

Applications

- All-purpose low-noise photoreceiver (O/E converter) for the MHz range
- Time resolved optical pulse and power measurements
- Laser intensity noise measurements (RIN)
- Optical front-end for oscilloscopes, spectrum analyzers, A/D converters and RF lock-in amplifiers

Block Diagram



SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

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### 200 MHz Variable Gain Photoreceiver

Available Versions

0E-300-SI-10-FST



Internal threaded coupler ring with 30 mm outer diameter (included)

0E-300-SI-10-FS



1.035"-40 threaded flange for free space applications compatible with many optical standard accessories and for use with various types of fiber connector adapters.

Optional: Fiber adapters PRA-FC and PRA-FSMA





25 mm dia. unthreaded flange for free space applications compatible with many optical standard accessories.

Related OE-300 Models	See separate datasheets for following models on www.femto.de:			
	0E-300-SI-30-FST	Si-PIN, ø 3 mm, 320 - 1000 nm 1.035"-40 threaded flange		
	0E-300-SI-30-FS	Si-PIN, ø 3 mm, 320 - 1000 nm 25 mm dia. unthreaded flange		
	0E-300-IN-01-FC	InGaAs-PIN, ø 80 µm, 900 - 1700 nm FC fiber receptacle only		
	0E-300-IN-03-FST	InGaAs-PIN, ø 300 μm, 800 - 1700 nm 1.035"-40 threaded flange		
	0E-300-IN-03-FS	InGaAs-PIN, ø 300 μm, 800 - 1700 nm 25 mm dia. unthreaded flange		
	0E-300-S	customized versions available on request		

F E T O

### 200 MHz Variable Gain Photoreceiver

Available Accessories

PRA-FSMA PRA-FC



fiber-adapter with external 1.035"-40 thread



post adapter plate, easy to mount on FEMTO photoreceiver series OE, FWPR, HCA-S and LCA-S



PRA-FC

PS-15



power supply, input: 100 - 240 VAC, output: ±15 VDC, +400/-250 mA

LUCI-10



compact digital I/O interface for USB remote control, supports opto-isolation of amplifier signal path from PC USB port, 16 digital outputs, 3 opto-isolated digital inputs, bus-powered operation

Specifications

Test conditions

 $V_s = \pm 15 \text{ V}, T_A = 25 \text{ °C}, \text{ system impedance} = 50 \Omega$ 

Gain

Transimpedance gain Gain accuracy

1 x 10<sup>2</sup> ... 1 x 10<sup>8</sup> V/A

±1 %

Frequency Response

Lower cut-off frequency Upper cut-off frequency

DC/100 Hz, switchable up to 200 MHz (see table below).

up to 200 MHz (see table below), switchable to 1 MHz or 10 MHz

Input

Noise equivalent power (NEP) Max. CW saturation power see table below see table below

Detector

Detector Active area Si-PIN photodiode 1 mm x 1 mm (1 mm²)

Spectral response Sensitivity R 400 - 1000 nm 0.58 A/W typ. @ 850 nm

Dark current

0.12 nA typ.

#### 200 MHz Variable Gain Photoreceiver

Specifications (continued)				
Performance Depending				
on Gain Setting				

Gain setting (low noise) (V/A)	10 <sup>2</sup>	10 <sup>3</sup>	104	10 <sup>5</sup>	10 <sup>6</sup>	10 <sup>7</sup>
Upper cut-off frequency (–3 dB)	200 MHz	80 MHz	14 MHz	3.5 MHz	1.8 MHz	220 kHz
NEP (/√Hz, @ 850 nm)	322 pW	25 pW	2.9 pW	740 fW	260 fW	78 fW
Measured at	20 MHz	8 MHz	1.4 MHz	350 kHz	180 kHz	22 kHz
Integrated input noise (RMS)*	7.5 µW	580 nW	35 nW	4.9 nW	1.3 nW	100 pW
CW sat. power (@ 850 nm)	10 mW	1.7 mW	170 µW	17 µW	1.7 µW	170 nW
Gain setting (high speed) (V/A)	10 <sup>3</sup>	10 <sup>4</sup>	10 <sup>5</sup>	10 <sup>6</sup>	10 <sup>7</sup>	108
Upper cut-off frequency (–3 dB)	175 MHz	80 MHz	14 MHz	3.5 MHz	1.8 MHz	220 kHz
NEP (/√Hz, @ 850 nm)	231 pW	10 pW	2.2 pW	670 fW	228 fW	76 fW
Measured at	18 MHz	8 MHz	1.4 MHz	350 kHz	180 kHz	22 kHz
Integrated input noise (RMS)*	4.5 µW	440 nW	31 nW	4.8 nW	1.3 nW	100 pW

<sup>\*</sup> The integrated input noise is measured with a shaded input in the full bandwidth ("FBW") setting (referred to 850 nm). The measurement bandwidth is 3 x the upper cut-off frequency at the specific gain setting; filter slope is a 1st order roll-off.

The input referred peak-peak noise can be calculated from the RMS noise as follows:

= PInput noise RMS X 6 PInput noise peak-to-peak

The output noise is given by: = PInput noise RMS x gain x R Uoutput noise RMS

 $U_{\text{Output noise peak-to-peak}} \quad = U_{\text{Output noise RMS}} \ x \ 6 = P_{\text{Input noise RMS}} \ x \ gain \ x \ R \ x \ 6$ 

The integrated noise will be reduced considerably by setting the low pass filter to "1 MHz" or "10 MHz" instead of "FBW". This is especially useful for continuous wave (CW) measurements.

Output

Output voltage range Output impedance Slew rate

 $\pm 1$  V (@ 50  $\Omega$  load), for linear amplification

 $50 \Omega$  (designed for  $50 \Omega$  load)

1000 V/µs

Max. output current ±40 mA

Output offset compensation adjustable by offset potentiometer and external control voltage, output offset compensation range min. ±100 mV

Ext. Offset Control

Control voltage range Offset control input impedance

±10 V  $15 \, \mathrm{k}\Omega$ 

Indicator LED

**Function** 

overload

Digital Control

Control input voltage range Control input current Overload output

LOW bit: -0.8 ... +1.2 V, HIGH bit: +2.3 ... +12 V 0 mA @ 0 V, 1.5 mA @ +5 V, 4.5 mA @ +12 V

non active: <0.4 V @ 0 ... -1 mA active: typ. 5 ... 5.1 V @ 0 ... 2 mA

**Power Supply** 

Supply voltage Supply current

+110/-90 mA (depends on operating conditions, recommended power supply capability min ±200 mA)

Stabilized power supply output

±12 V, max. 20 mA, +5 V, max. 150 mA

Case

Weight

320 g (0.74 lb.)

Material AlMg4.5Mn, nickel-plated

# 200 MHz Variable Gain Photoreceiver

Specifications (continued)					
Input Flange	Material	1.4305 stainless steel, glass bead blasted (1.035"-40 threaded flange) AIMg4.5Mn, nickel-plated (25 mm dia. unthreaded flange)			
Coupler Ring	Material	1.4305 stainless steel, glass bead blasted			
DC Monitor Output	Monitor output gain	Mode Monitor gain  Low noise Gain setting divided by -1  High speed Gain setting divided by -10			
	Monitor output polarity Monitor output voltage range Monitor output bandwidth Monitor output impedance	inverting $ \pm 1 \text{ V } (@ \geq 1 \text{ M}\Omega \text{ load}) $ DC 1 kHz $ 1 \text{ k}\Omega \text{ (designed for } \geq 1 \text{ M}\Omega \text{ load}) $			
Temperature Range	Storage temperature Operating temperature	-40 +80 °C 0 +60 °C			
Absolute Maximum Ratings	Max. CW power (averaged) Digital control input voltage Analog control input voltage Power supply voltage	12 mW -5 V/+16 V relative to digital ground DGND (pin 9) ±15 V relative to analog ground AGND (pin 3) ±20 V			
Connectors	Input	OE-300-SI-10-FST 1.035"-40 threaded flange for free space applications and for use with various types of fiber connector adapters			
		OE-300-SI-10-FS 25 mm unthreaded round flange for free space applications			
	Output	BNC jack (female)			
	Power supply	Lemo® series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52)			
		Pin 1: +15 V Pin 2: -15 V Pin 3: GND PIN 2 -Vs PIN 3 GND			
	Control port	Sub-D 25-pin, female, qual. class 2 Pin 1: +12 V (stabilized power supply output) Pin 2: -12 V (stabilized power supply output) Pin 3: AGND (analog ground for pins 1 - 8) Pin 4: +5 V (stabilized power supply output) Pin 5: digital output: overload (referred to pin 3) Pin 6: DC Monitor output Pin 7: NC (= not connected) Pin 8: output offset control voltage input Pin 9: DGND (ground for digital control pins 10 - 16) Pin 10: digital control input: gain, LSB Pin 11: digital control input: gain, MSB Pin 12: digital control input: gain, MSB Pin 13: digital control input: high speed / low noise Pin 15: upper cut-off frequency limit 10 MHz Pin 16: upper cut-off frequency limit 1 MHz Pin 17 - 25: NC (= not connected)			

# 200 MHz Variable Gain Photoreceiver

Scope of Delivery	OE-300-SI-10, threaded coupler ring ("FST" version only), Lemo® 3-pin connector, datasheet, transport package						
Remote Control Operation	General	by a logical O remote contro "Remote", "D select the des corresponding Mixed operati	ol input bits are R function to the ol set the corres C", "L" (low no sired setting via g digital inputs. on, e.g. local A n setting, is als	ne local sy sponding ise mode a bit coo C/DC set	witch settin local switcl ) and "FBW de at the ting and re	gs. For hes to I", and	
	Gain setting		High speed Gain (V/A) Pin 14=HIGH	Pin 12 MSB	Pin 11	Pin 10 LSB	
		10 <sup>2</sup>	10 <sup>3</sup>	LOW	LOW	LOW	
		10 <sup>3</sup>	10 4	LOW	LOW	HIGH	
		10 4	10 <sup>5</sup>	LOW	HIGH	LOW	
		10 <sup>5</sup>	10 <sup>6</sup>	LOW	HIGH	HIGH	
		10 <sup>6</sup>	10 <sup>7</sup>	HIGH	LOW	LOW	
		10 <sup>7</sup>	108	HIGH	LOW	HIGH	
	AC/DC setting	Coupling DC AC	Pin 13 LOW HIGH				
	Low pass filter setting	Upper cut-off full bandwidth 10 MHz 1 MHz		Pin 15 LOW HIGH LOW	Pin 16 LOW LOW HIGH		
	High speed / low noise setting	Mode low noise mod high speed m		Pin 14 LOW HIGH			
Spectral Responsivity	0.7						
	0.6 0.5 0.4 0.3 0.2 0.1 0 400 500	600 700 Wave	800 elength - nm	900	1000	) 1100	

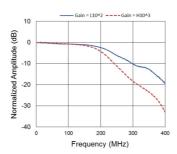
SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

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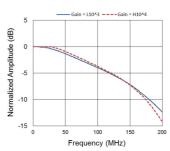
Typical Performance Characteristic Frequency response

$$V_{\text{Supply}} = \pm 15 V_{\text{DC}}; R_{\text{Load}} = 50 \Omega$$

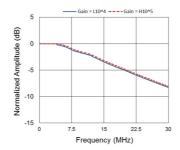
Gain setting: L10<sup>2</sup>, H10<sup>3</sup>



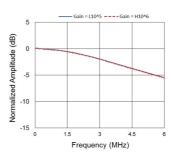
Gain setting: L10<sup>3</sup>, H10<sup>4</sup>



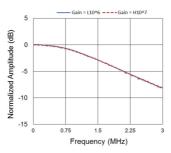
Gain setting: L10<sup>4</sup>, H10<sup>5</sup>



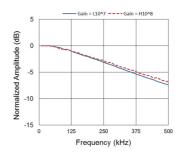
Gain setting: L10<sup>5</sup>, H10<sup>6</sup>



Gain setting: L10<sup>6</sup>, H10<sup>7</sup>



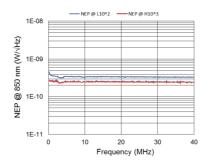
Gain setting: L10<sup>7</sup>, H10<sup>8</sup>



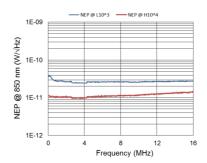
# 200 MHz Variable Gain Photoreceiver

Typical Performance Characteristic (continued) Input noise equivalent power (NEP)

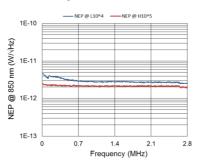
Gain setting L10<sup>2</sup>, H10<sup>3</sup>



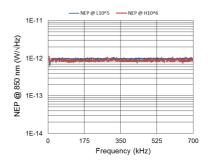
Gain setting L103, H104



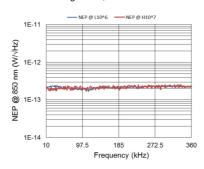
Gain setting: L10<sup>4</sup>, H10<sup>5</sup>



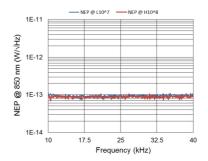
Gain setting: L10<sup>5</sup>, H10<sup>6</sup>



Gain setting: L10<sup>6</sup>, H10<sup>7</sup>

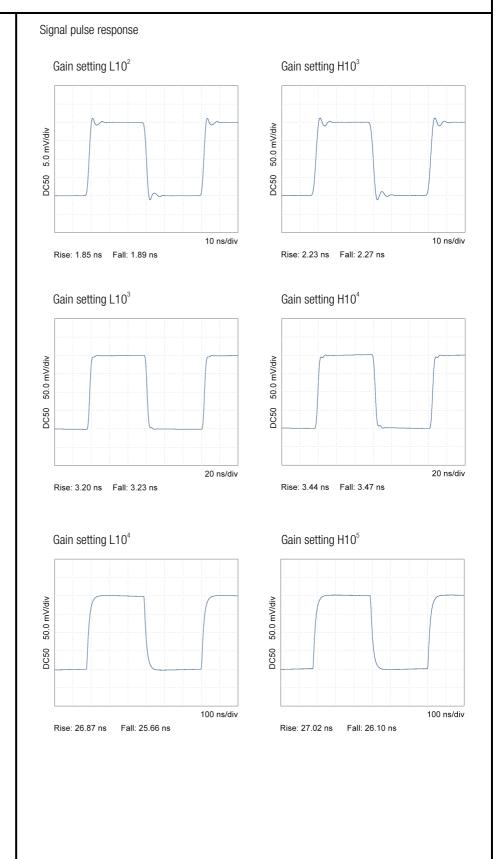


Gain setting: L10<sup>7</sup>, H10<sup>8</sup>



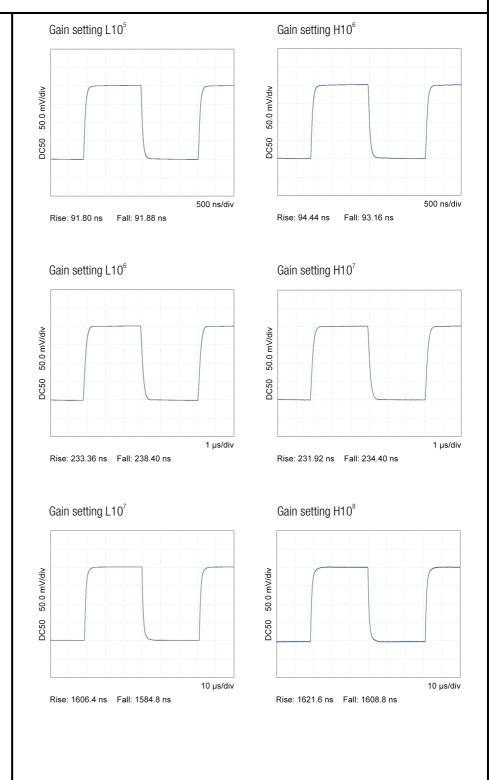
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Typical Performance Characteristic (continued)

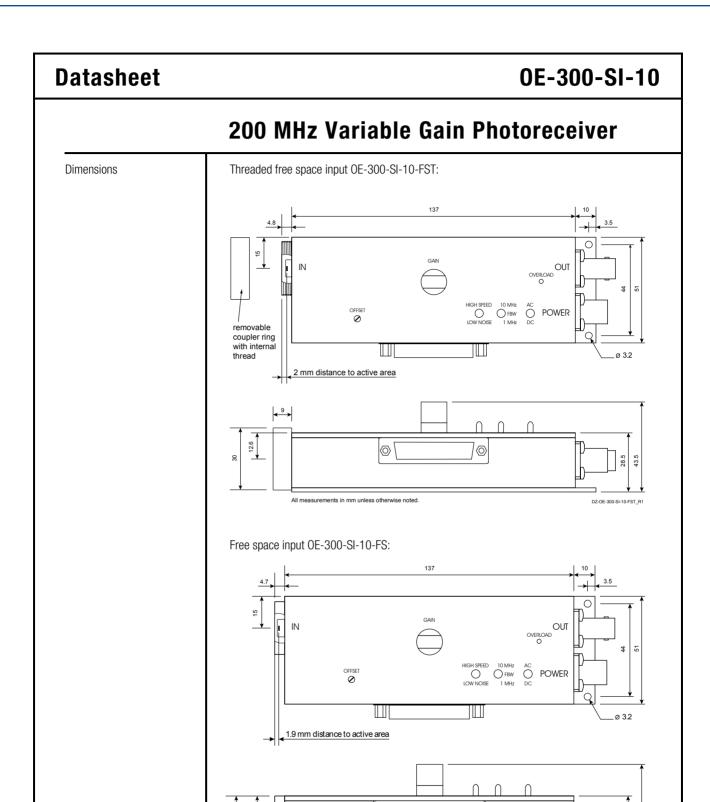


### 200 MHz Variable Gain Photoreceiver

Typical Performance Characteristic (continued)







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